

# M74HC165

### 8-bit PISO shift register

#### Features

- High speed:
  - t\_{PD} = 15 ns (typ.) at V\_{CC} = 6 V
- Low power dissipation:
   I<sub>CC</sub> = 4 μA (max.) at T<sub>A</sub> = 25 °C
- High noise immunity:
- $V_{\text{NIH}} = V_{\text{NIL}} = 28 \% V_{\text{CC}}$  (Min.)
- Symmetrical output impedance: |I<sub>OH</sub>| = I<sub>OL</sub> = 4 mA (min)
- Balanced propagation delays: t<sub>PLH</sub> ≅ t<sub>PHL</sub>
- Wide operating voltage range:
   V<sub>CC</sub> (opr) = 2 V to 6 V
- Pin and function compatible with 74 series 165



### Description

The M74HC165 is a high speed CMOS 8-bit PISO (parallel-in-serial-out) shift register fabricated with silicon gate C<sup>2</sup>MOS technology. This device contains eight clocked master slave RS flip-flops connected as a shift register, with auxiliary gating to provide overriding asynchronous parallel entry. The parallel data enter when the shift/load input is low and can change while shift/load is low, provided that the recommended set-up and hold times are observed. For clocked operation, shift/load must be high. The two clock inputs perform identically: one can be used as a clock inhibit by applying a high signal, to allow this operation clocking is accomplished through a 2-input nor gate. To avoid double clocking, however, the inhibit signal should only go high while the clock is high. Otherwise the rising inhibit signal causes the same response as rising clock edge. All inputs are equipped with protection circuits against static discharge and transient excess voltage.

#### Table 1. Device summary

Order code	Package	Packaging				
M74HC165B1R	DIP-16	Tube				
M74HC165RM13TR	SO-16	Tape and reel				
M74HC165TTR	TSSOP16	Tape and reel				

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## 1 Logic symbols and I/O equivalent circuit





#### Figure 2. Input and output equivalent circuit



## 2 Pin settings

#### 2.1 Pin connection





### 2.2 Pin description

#### Table 2.Pin description

Pin number	Symbol	Name and function
1	SHIFT/LOAD	Data inputs
2	CLOCK	Clock input (low to high, edge triggered)
7	QH	Complementary output
9	QH	Serial output
10	SI	Serial input
11, 12, 13, 14, 3, 4, 5, 6	A to H	Parallel data inputs
15	CLOCK INH	Clock inhibit
8	GND	Ground (0 V)
16	V <sub>CC</sub>	Positive supply voltage



### 3 Logic states

#### 3.1 Truth table

Table 3.	Truth table
	Inputs

		Internal	Outputs						
Shift /Load	Clock INH	Clock	SI	АН	QA	QB	QH		
L	Х	Х	Х	ah	а	b	h		
Н	L		Н	Х	Н	H QAn			
Н	L		L	Х	L QAn		QGn		
Н		L	Н	Х	Н	QAn	QGn		
Н		L	L	Х	L	L QAn (			
Н	Х	Н	Х	Х	No change				
Н	Н	Х	Х	Х	No change				

Note: a......h : the level of steady input voltage at inputs a through respectively QAn - QGn : the level of QA - QG, respectively. Before the most recent transition of the clock.

#### 3.2 Logic diagram



Figure 4. Logic diagram

Note:

This logic diagram has not to be used to estimate propagation delays



### 3.3 Timing chart







### 4 Maximum rating

Stressing the device above the rating listed in the "absolute maximum ratings" table may cause permanent damage to the device. these are stress ratings only and operation of the device at these or any other conditions above those indicated in the operating sections of this specification is not implied. exposure to absolute maximum rating conditions for extended periods may affect device reliability. refer also to the STMicroelectronics sure program and other relevant quality documents.

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply voltage	-0.5 to +7	V
VI	DC input voltage	-0.5 to V <sub>CC</sub> + 0.5	V
Vo	DC output voltage	-0.5 to V <sub>CC</sub> + 0.5	V
Ι <sub>ΙΚ</sub>	DC input diode current	±20	mA
I <sub>OK</sub>	DC output diode current	±20	mA
Ι <sub>Ο</sub>	DC output current	±25	mA
I <sub>CC</sub> or I <sub>GND</sub>	DC V <sub>CC</sub> or ground current	±50	mA
PD	Power dissipation	500 <sup>(1)</sup>	mW
T <sub>stg</sub>	Storage temperature	-65 to +150	°C
ΤL	Lead temperature (10 sec)	300	°C

Table 4. Absolute maximum ratings

1. (\*) 500 mW at 65  $^\circ$  C; derate to 300 mW by 10 mW/ $^\circ$  C from 65  $^\circ$  C to 85  $^\circ$  C

#### 4.1 Recommended operating conditions

 Table 5.
 Recommended operating conditions

Symsbol	Parameter	Value	Unit	
V <sub>CC</sub>	Supply voltage		2 to 6	V
VI	Input voltage		0 to V <sub>CC</sub>	V
Vo	Output voltage	0 to V <sub>CC</sub>	V	
T <sub>op</sub>	Operating temperature	-55 to 125	°C	
		$V_{CC} = 2.0 V$	0 to 1000	ns
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall time	$V_{CC} = 4.5 V$	0 to 500	ns
		$V_{CC} = 6.0 V$	0 to 400	ns

# 5 Electrical characteristics

Table 6.	DC specifications

		Test condition		Value							
Symbol	Parameter	v <sub>cc</sub>		T <sub>A</sub> = 25°C			-40 to	₀ 85°C	-55 to	125°C	Unit
		(V)		Min	Тур	Max	Min	Max	Min	Max	
		2.0		1.5			1.5		1.5		
$V_{IH}$	High level input voltage	4.5		3.15			3.15		3.15		V
		6.0		4.2			4.2		4.2		
		2.0				0.5		0.5		0.5	
V <sub>IL</sub>	Low level input voltage	4.5				1.35		1.35		1.35	V
	6.0				1.8		1.8		1.8		
		2.0	I <sub>O</sub> = -20 μA	1.9	2.0		1.9		1.9		
		4.5	I <sub>O</sub> = -20 μA	4.4	4.5		4.4		4.4		
V <sub>OH</sub>	High level output voltage	6.0	I <sub>O</sub> = -20 μA	5.9	6.0		5.9		5.9		V
		4.5	l <sub>O</sub> = -4.0 mA	4.18	4.31		4.13		4.10		
		6.0	l <sub>O</sub> = -5.2 mA	5.68	5.8		5.63		5.60		
		2.0	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	
		4.5	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	
V <sub>OL</sub>	Low level output voltage	6.0	I <sub>O</sub> = 20 μA		0.0	0.1		0.1		0.1	V
		4.5	I <sub>O</sub> = 4.0 mA		0.17	0.26		0.33		0.40	
		6.0	I <sub>O</sub> = 5.2 mA		0.18	0.26		0.33		0.40	
I <sub>I</sub>	Input leakage current	6.0	$V_I = V_{CC}$ or GND			±0.1		±1		±1	μΑ
I <sub>CC</sub>	Quiescent supply current	6.0	$V_I = V_{CC}$ or GND			4		40		80	μΑ



		Te	est condition	Value							
Symbol	Parameter	v <sub>cc</sub>		т	A = 25°	°C	-40 te	o 85°C	-55 to	125°C	Unit
		(V)		Min	Тур	Max	Min	Max	Min	Max	
	-	2.0			30	75		95		110	
t <sub>TLH</sub> t <sub>THL</sub>	Output transition time	4.5			8	15		19		22	ns
		6.0			7	13		16		19	
	Propagation delay	2.0			55	150		190		225	
t <sub>PLH</sub> t <sub>PHL</sub>	time	4.5			18	30		38		45	ns
	$(CLOCK - QH, \overline{Q}H)$	6.0			15	26		33		38	
	Propagation delay	2.0			65	165		205	250		
t <sub>PLH</sub> t <sub>PHL</sub>	time (SHIFT/ <u>LOAD</u> -	4.5			21	33		41		50	ns
	QH, QH)	6.0			18	28		35		43	
	Propagation delay	2.0			52	135		170		205	
t <sub>PLH</sub> t <sub>PHL</sub>	time	4.5			17	27		34		41	ns
	(H - QH, <u>Q</u> H)	6.0			14	23		29		35	
fMAX Maximum clock frequency	2.0		7.4	15		6.0		4.8			
		4.5		37	60		30		24		MHz
		6.0		44	71		35		28		
	Minimum pulse	2.0			24	75		95		110	
t <sub>W(H)</sub> t <sub>W(L)</sub>	width	4.5			6	15		19		22	ns
VV(L)	(CLOCK)	6.0			5	13		16		19	
	Minimum pulse	2.0			32	75		95		110	
t <sub>W(L)</sub>	width	4.5			8	15		19		22	ns
	(SHIFT/LOAD)	6.0			7	13		16		19	
	Minimum set-up	2.0			24	75		95		110	
	time (PI-SHIFT/ <u>LOAD</u> )	4.5			6	15		19		22	20
<sup>I</sup> s (SI - CLOCK) (SHIFT/LOAD -		6.0			5	13		16		19	ns
	Minimum hold time	2.0				0		0		0	
t <sub>h</sub>	(PI - SHIFT/LOAD) (SI - CLOCK)	4.5				0		0		0	ns
'n	(SHIFT/LOAD - CK)	6.0				0		0		0	
	Minimum removal	2.0			20	75		95		110	
t <sub>REM</sub>	time	e 4.5 5 15 19		22	ns						
	(CLOCK - CK INH)	6.0			4	13		16		19	

### Table 7.AC electrical characteristics ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ns}$ )



Symbol Paran		Test condition		Value							
	Parameter	V <sub>cc</sub> (V)		T <sub>A</sub> = 25 °C		T <sub>A</sub> = 25 °C -		-40 to 85 °C		-55 to 125 °C	
			Min	Тур	Max	Min	Max	Min	Max		
C <sub>IN</sub>	Input capacitance	5.0			5	10		10		10	pF
C <sub>PD</sub>	Power dissipation capacitance <sup>(1)</sup>	5.0			55						pF

1.  $C_{PD}$  is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation.  $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$ 



## 6 Test circuit





 $C_L = 50 \text{ pF}$  or equivalent (includes jig and probe capacitance)  $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )



## 7 Waveforms









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# Figure 9. Minimum pulse width (S/ $\overline{L}$ ), propagation delay times (f = 1 MHz; 50% duty cycle)



Figure 10. Setup and hold time (PI to S/L) (f = 1 MHz; 50% duty cycle)



Figure 11. Minimum removal time (CK INH to CK) (f = 1 MHz; 50% duty cycle)



### 8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK<sup>®</sup> packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.



	Plastic DIP-16 (0.25) MECHANICAL DATA						
DIM.	mm.			inch			
Dim.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
a1	0.51			0.020			
В	0.77		1.65	0.030		0.065	
b		0.5			0.020		
b1		0.25			0.010		
D			20			0.787	
E		8.5			0.335		
е		2.54			0.100		
e3		17.78			0.700		
F			7.1			0.280	
I			5.1			0.201	
L		3.3			0.130		
Z			1.27			0.050	





DIM.		mm.		inch		
DINI.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX
А			1.75			0.068
a1	0.1		0.25	0.004		0.010
a2			1.64			0.063
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	
c1			45°	(typ.)	•	•
D	9.8		10	0.385		0.393
E	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		8.89			0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
М			0.62			0.024



TSSOP16 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.
А			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004		0.0079
D	4.9	5	5.1	0.193	0.197	0.201
Е	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
е		0.65 BSC			0.0256 BSC	
К	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



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	Tape & Reel SO-16 MECHANICAL DATA						
DIM.	mm.			inch			
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
Ν	60			2.362			
Т			22.4			0.882	
Ao	6.45		6.65	0.254		0.262	
Во	10.3		10.5	0.406		0.414	
Ko	2.1		2.3	0.082		0.090	
Po	3.9		4.1	0.153		0.161	
Р	7.9		8.1	0.311		0.319	





	Tape & Reel SSOP16 MECHANICAL DATA						
DIM	mm.			inch			
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.	
А			330			12.992	
С	12.8		13.2	0.504		0.519	
D	20.2			0.795			
Ν	60			2.362			
Т			22.4			0.882	
Ao	8.4		8.6	0.331		0.339	
Во	6.7		6.9	0.264		0.272	
Ko	2.9		3.1	0.114		0.122	
Po	3.9		4.1	0.153		0.161	
Р	11.9		12.1	0.468		0.476	



# 9 Revision history

#### Table 9. Document revision history

Date	Revision	Changes
9-Jul-2001	3	Final release.
21-Mar-2007	4	The document has been reformatted, updated <i>Table 2: Pin description on page 4</i>
26-May-2008	5	Removed: M74HC165M1R order code. Minor changes in the text. Added: SO-16 and TSSOP16 tape and reel specifications.



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